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International
IOR Rectifier

70HF(R) SERIES

STANDARD RECOVERY DIODES **Stud Version**

70 A

Features

- High surge current capability
- Designed for a wide range of applications
- Stud cathode and stud anode version
- Leaded version available
- Types up to 1600V V_{RRM}

TypicalApplications

- Battery charges
- Converters
- Power supplies
- Machine tool controls

Major Ratings and Characteristics

Parameters		70HF(R)		Units
		10 to 120	140 to 160	
$I_{F(AV)}$		70	70	A
	@ T_C	140	110	°C
$I_{F(RMS)}$		110		A
I_{FSM}	@ 50Hz	1200		A
	@ 60Hz	1250		A
I^2t	@ 50Hz	7100		A^2s
	@ 60Hz	6540		A^2s
V_{RRM}	range	100 to 1200	1400 to 1600	V
T_J	range	- 65 to 180	- 65 to 150	°C

case style
DO-203AB (DO-5)

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ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM}, maximum repetitive peak reverse voltage V	V_{RSM}, maximum non-repetitive peak reverse voltage V	$V_{R(BR)}$, minimum avalanche voltage V (1)	I_{RRM} max. @ $T_J = T_J$ max. mA
70HF(R)	10	100	200	--	15
	20	200	300	--	
	40	400	500	500	
	60	600	720	725	9
	80	800	960	950	
	100	1000	1200	1150	
	120	1200	1440	1350	
	140	1400	1650	1550	4.5
	160	1600	1900	1750	

(1) Avalanche version only available from V_{RRM} 400V to 1600V.

Forward Conduction

Parameter		70HF(R) 10 to 120	70HF(R) 140 to 160	Units	Conditions		
$I_{F(AV)}$	Max. average forward current @ Case temperature	70 140	70 110	A °C	180° conduction, half sine wave		
$I_{F(RMS)}$	Max. RMS forward current	110		A	DC @ T_C = 25°C		
P_R	Maximum non-repetitive peak reverse power	20		K · W	10µs square pulse, $T_J = T_J$ max. **see note (2)**		
I_{FSM}	Max. peak, one-cycle forward, non-repetitive surge current	1200 1250 1000 1050		A	t = 10ms t = 8.3ms t = 10ms t = 8.3ms	No voltage reapplied 100% V_{RRM} reapplied	Sinusoidal half wave, Initial $T_J = T_J$ max.
I^2t	Maximum I^2t for fusing	7100 6450 5000 4550		A^2s	t = 10ms t = 8.3ms t = 10ms t = 8.3ms	No voltage reapplied 100% V_{RRM} reapplied	
$I^2\sqrt{t}$	Maximum $I^2\sqrt{t}$ for fusing	71000		$A^2\sqrt{s}$	t = 0.1 to 10ms, no voltage reapplied		
$V_{F(TO)1}$	Low level value of threshold voltage	0.79		V	(16.7% x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ max.		
$V_{F(TO)2}$	High level value of threshold voltage	1.00		V	(I > π x $I_{F(AV)}$), $T_J = T_J$ max.		
r_{f1}	Low level value of forward slope resistance	2.33		mΩ	(16.7% x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ max.		
r_{f2}	High level value of forward slope resistance	1.53		mΩ	(I > π x $I_{F(AV)}$), $T_J = T_J$ max.		
V_{FM}	Max. forward voltage drop	1.35		V	I_{pk} = 220A, T_J = 25°C, t_p = 10ms sinusoidal wave		

(2) Available only for Avalanche version, all other parameters the same as 70HF.

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Thermal and Mechanical Specifications

Parameter		70HF(R) 10 to 120	70HF(R) 140 to 160	Units	Conditions
T_J	Max. junction operating temperature range	-65 to 180	-65 to 150	°C	
T_{stg}	Max. storage temperature range	-65 to 180	-65 to 150		
R_{thJC}	Max. thermal resistance, junction to case	0.45		K/W	DC operation
R_{thCS}	Max. thermal resistance, case to heatsink	0.25			Mounting surface, smooth, flat and greased
T	Max. allowed mounting torque ±10%	2.3 - 3.4		Nm	Not lubricated threads
		20 - 30		lbf·in	
wt	Approximate weight	17 (0.6)		g (oz)	
	Case style	DO-203AB (DO5)			See Outline Table

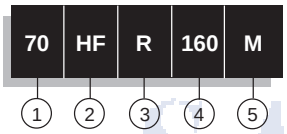
ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistence R_{thJC} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.08	0.06	K/W	$T_J = T_J$ max.
120°	0.10	0.11		
90°	0.13	0.14		
60°	0.19	0.20		
30°	0.30	0.30		

Ordering Information Table

Device Code



1 - 70 = Standard device
71 = Not isolated lead
72 = Isolated lead with silicone sleeve
(Red = Reverse polarity)
(Blue = Normal polarity)

2 - HF = Standard diode
HA = Avalanche diode

3 - None = Stud Normal Polarity (Cathode to Stud)
R = Stud Reverse Polarity (Anode to Stud)

4 - Voltage code: Code x 10 = V_{RRM} (See Voltage Ratings table)

5 - None = Stud base DO-203AB (DO-5) 1/4" 28UNF-2A
M = Stud base DO-203AB (DO-5) M6 X 1 - (Not available for Avalanche diodes)

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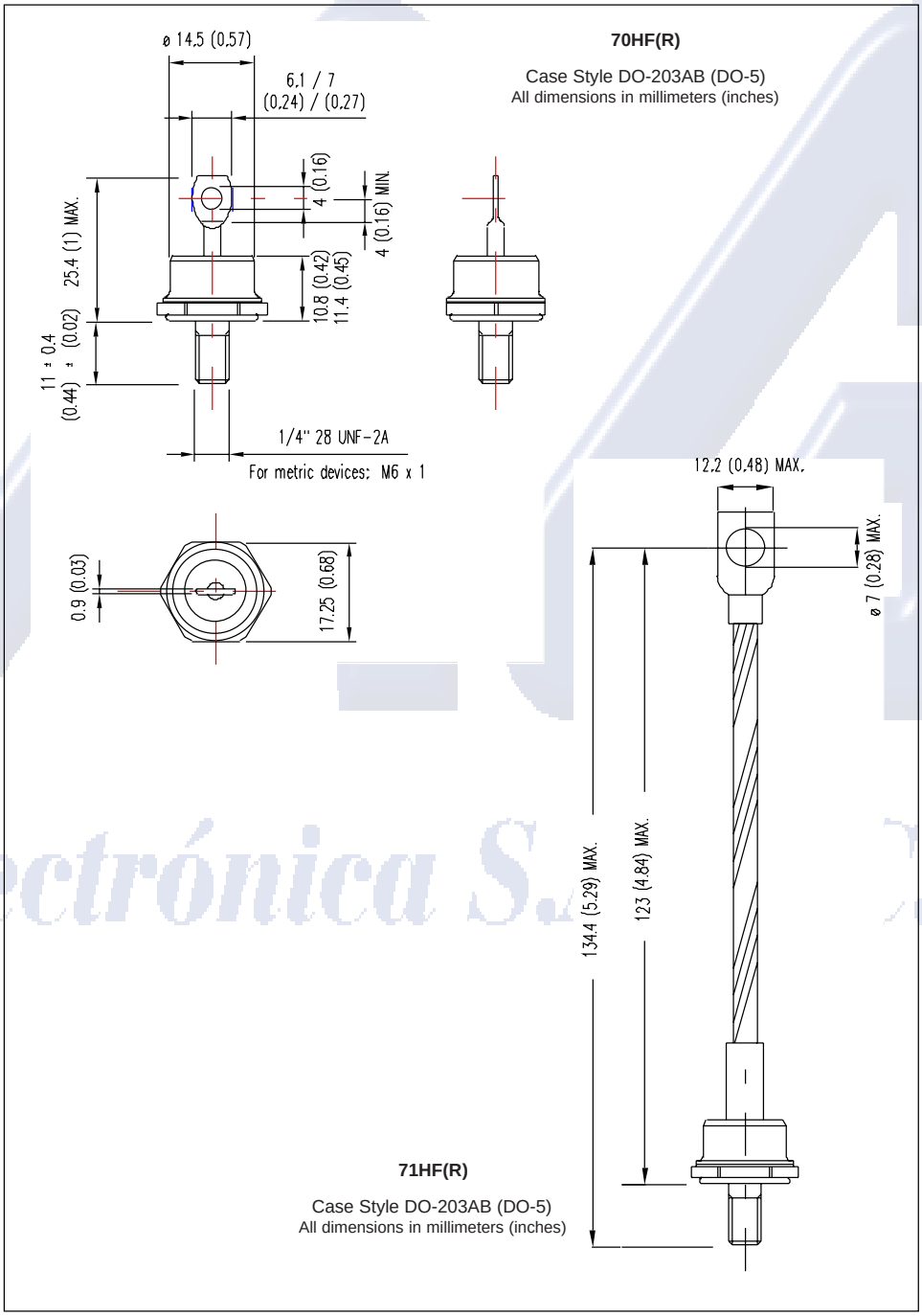
Outlines Table



70HF(R)

Case Style DO-203AB (DO-5)
All dimensions in millimeters (inches)

71HF(R)

Case Style DO-203AB (DO-5)
All dimensions in millimeters (inches)

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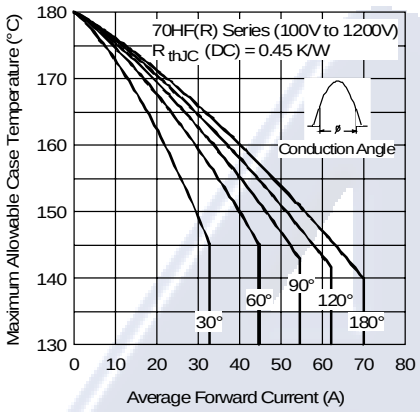

Fig. 1 - Current Ratings Characteristics

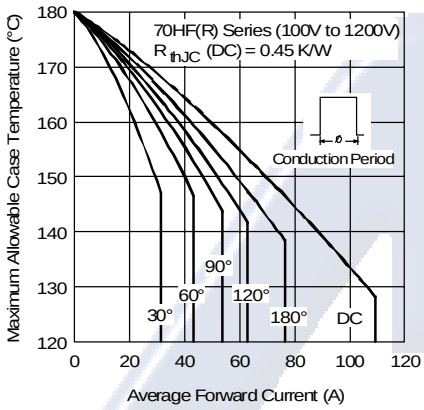

Fig. 2 - Current Ratings Characteristics

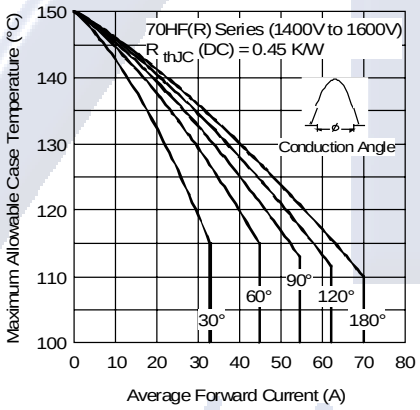

Fig. 3 - Current Ratings Characteristics

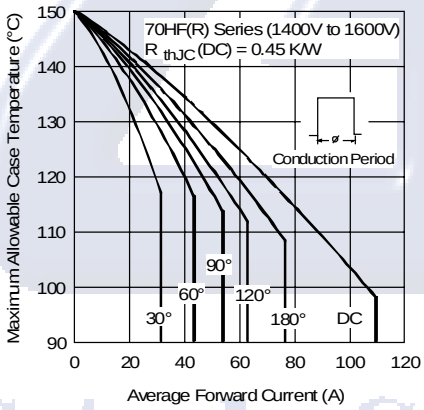

Fig. 4 - Current Ratings Characteristics

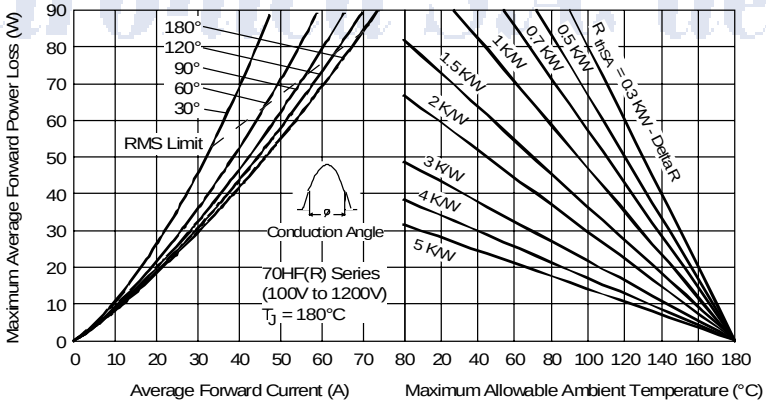

Fig. 5 - Forward Power Loss Characteristics

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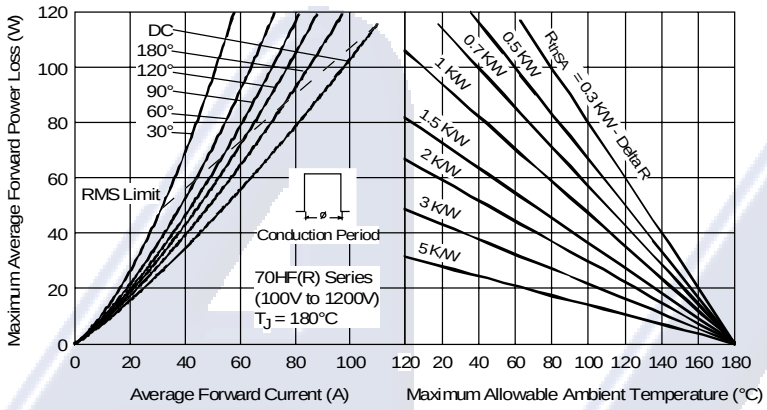

Fig. 6 - Forward Power Loss Characteristics

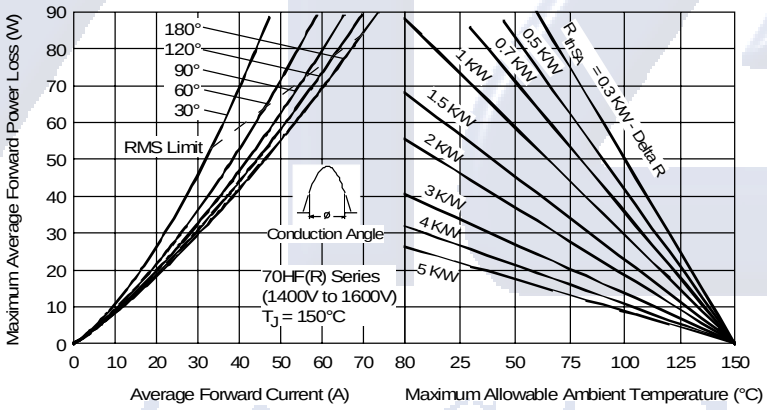

Fig. 7 - Forward Power Loss Characteristics

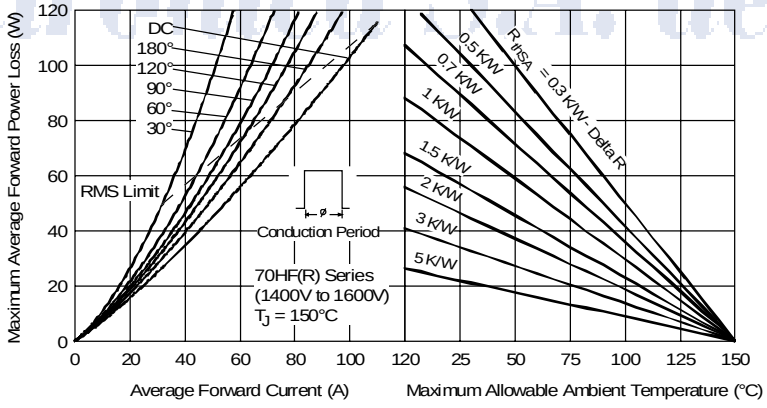

Fig. 8 - Forward Power Loss Characteristics

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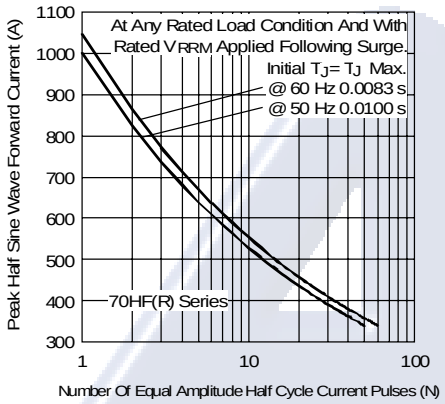

Fig. 9 - Maximum Non-Repetitive Surge Current

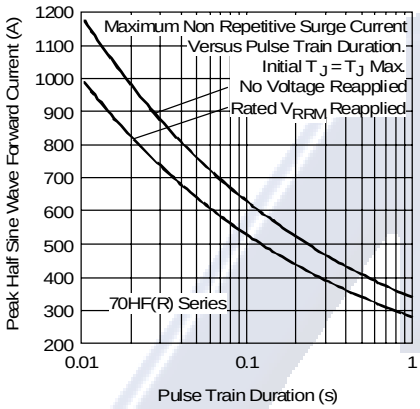

Fig. 10 - Maximum Non-Repetitive Surge Current

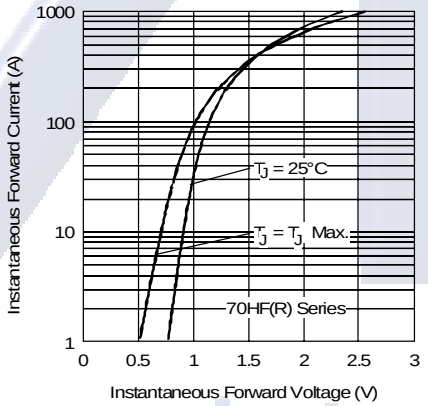

Fig. 11 - Forward Voltage Drop Characteristics

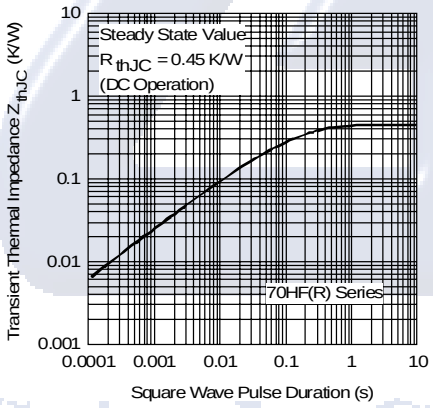

Fig. 12 - Thermal Impedance Z_{thJC} Characteristics

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